

Low-Voltage CMOS Dual D-Type Flip-Flop

With 5 V-Tolerant Inputs

MC74LCX74

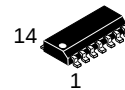
The MC74LCX74 is a high performance, dual D-type flip-flop with asynchronous clear and set inputs and complementary (O , $\overline{O}$) outputs. It operates from a 1.65 to 5.5 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows MC74LCX74 inputs to be safely driven from 5.0 V devices.

The MC74LCX74 consists of 2 edge-triggered flip-flops with individual D-type inputs. The flip-flop will store the state of individual D inputs, that meet the setup and hold time requirements, on the LOW-to-HIGH Clock (CP) transition.

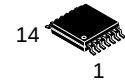
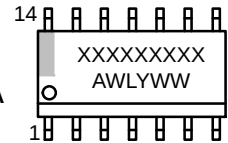
Features

- Designed for 1.65 V to 5.5 V V_{CC} Operation
- 5.0 V Tolerant Inputs – Interface Capability With 5.0 V TTL Logic
- LVTTTL Compatible
- LVC MOS Compatible
- 24 mA Balanced Output Sink and Source Capability at $V_{CC} = 3.0$ V
- Near Zero Static Supply Current in All Three Logic States (10 μ A) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 100 mA
- ESD Performance: Human Body Model >2000 V
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

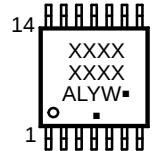
MARKING DIAGRAMS



SOIC-14
D SUFFIX
CASE 751A



TSSOP-14
DT SUFFIX
CASE 948G



XXXXXX = Specific Device Code
A = Assembly Location
L, WL = Wafer Lot
Y = Year
W, WW = Work Week
■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

MC74LCX74

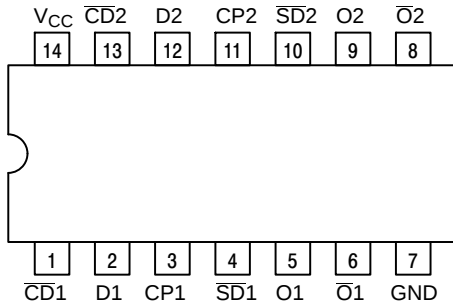


Figure 1. Pinout: 14-Lead (Top View)

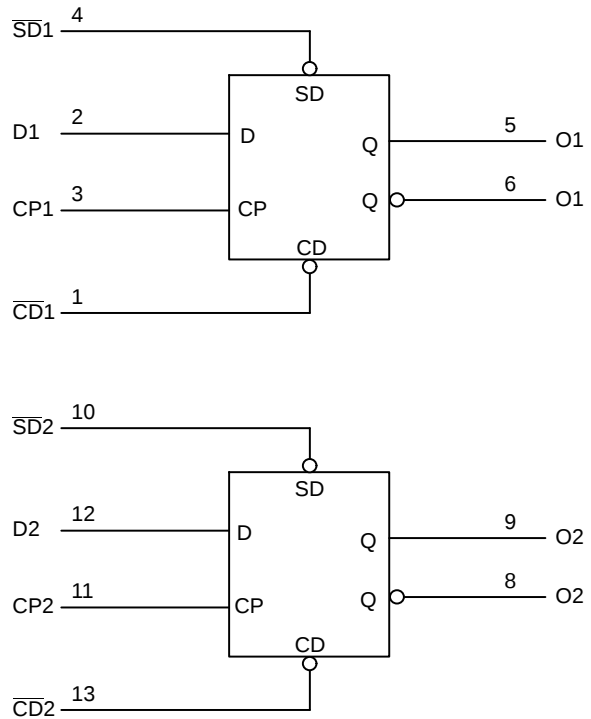


Figure 2. Logic Diagram

PIN NAMES

Pins	Function
CP1, CP2	Clock Pulse Inputs
D1-D2	Data Inputs
$\overline{CD}1$, $\overline{CD}2$	Direct Clear Inputs
$\overline{SD}1$, $\overline{SD}2$	Direct Set Inputs
O _n - $\overline{O}$ _n	Outputs

TRUTH TABLE

Inputs				Outputs		Operating Mode
$\overline{SD}n$	$\overline{CD}n$	CPn	Dn	O _n	$\overline{O}n$	
L	H	X	X	H	L	Asynchronous Set Asynchronous Clear Undetermined
H	L	X	X	L	H	
L	L	X	X	H	H	
H	H	↑	h	H	L	Load and Read Register
H	H	↑	l	L	H	
H	H	↯	X	NC	NC	Hold

H = High Voltage Level

h = High Voltage Level One Setup Time Prior to the Low-to-High Clock Transition

L = Low Voltage Level

l = Low Voltage Level One Setup Time Prior to the Low-to-High Clock Transition

NC = No Change

X = High or Low Voltage Level and Transitions are Acceptable

↑ = Low-to-High Transition

↯ = Not a Low-to-High Transition

For I_{CC} reasons, DO NOT FLOAT Inputs

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MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V_{CC}	DC Supply Voltage		-0.5 to +6.5	V
V_I	DC Input Voltage (Note 1)		-0.5 to +6.5	V
V_O	DC Output Voltage (Note 1)	Active-Mode (High or Low State)	-0.5 to $V_{CC} + 0.5$	V
		Tri-State Mode	-0.5 to +6.5	
		Power-Down Mode ($V_{CC} = 0$ V)	-0.5 to +6.5	
I_{IK}	DC Input Diode Current $V_I < GND$		-50	mA
I_{OK}	DC Output Diode Current $V_O < GND$		-50	mA
I_O	DC Output Source/Sink Current		± 50	mA
I_{CC} or I_{GND}	DC Supply Current per Supply Pin or Ground Pin		± 100	mA
T_{STG}	Storage Temperature Range		-65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
T_J	Junction Temperature under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 1)	SOIC-14	116	°C/W
		TSSOP-14	150	
P_D	Power Dissipation in Still Air at 125°C	SOIC-14	116	mW
		TSSOP-14	833	
MSL	Moisture Sensitivity		Level 1	
F_R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V_{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model	2000	V
		Charged Device Model	N/A	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I_O absolute maximum rating must be observed.
2. Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Typ	Max	Unit
V_{CC}	Supply Voltage	Operating	1.65	2.5, 3.3	5.5	V
		Data Retention Only	1.5	2.5, 3.3	5.5	
V_I	Digital Input Voltage		0	-	5.5	V
V_O	Output Voltage	Active Mode (High or Low State)	0	-	V_{CC}	V
		Tri-State Mode	0	-	5.5	
		Power Down Mode ($V_{CC} = 0$ V)	0	-	5.5	
T_A	Operating Free-Air Temperature		-40	-	+125	°C
t_r, t_f	Input Rise or Fall Rate	$V_{CC} = 1.65$ V to 1.95 V	0	-	20	nS/V
		$V_{CC} = 2.3$ V to 2.7 V	0	-	20	
		V_{IN} from 0.8 V to 2.0 V, $V_{CC} = 3.0$ V	0	-	10	
		$V_{CC} = 4.5$ V to 5.5 V	0	-	5	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

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DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = -40°C to +85°C		T _A = -40°C to +125°C		Unit
				Min	Max	Min	Max	
V _{IH}	HIGH Level Input Voltage		1.65 – 1.95	0.65 x V _{CC}	–	0.65 x V _{CC}	–	V
			2.3 – 2.7	1.7	–	1.7	–	
			3.0 – 3.6	2.0	–	2.0	–	
			4.5 – 5.5	0.70 x V _{CC}	–	0.70 x V _{CC}	–	
V _{IL}	LOW Level Input Voltage		1.65 – 1.95	–	0.35 x V _{CC}	–	0.35 x V _{CC}	V
			2.3 – 2.7	–	0.7	–	0.7	
			3.0 – 3.6	–	0.8	–	0.8	
			4.5 – 5.5	–	0.30 x V _{CC}	–	0.30 x V _{CC}	
V _{OH}	High-Level Output Voltage	V _I = V _{IH} or V _{IL}	1.65 to 5.5	V _{CC} – 0.1	–	V _{CC} – 0.1	–	V
		I _{OH} = –100 µA	1.65	1.29	–	1.29	–	
		I _{OH} = –4 mA	2.3	1.8	–	1.8	–	
		I _{OH} = –8 mA	2.7	2.2	–	2.2	–	
		I _{OH} = –12 mA	3.0	2.4	–	2.4	–	
		I _{OH} = –16 mA	3.0	2.2	–	2.2	–	
		I _{OH} = –24 mA	4.5	3.7	–	3.7	–	
		I _{OH} = –32 mA						
V _{OL}	Low-Level Output Voltage	V _I = V _{IH} or V _{IL}	1.65 to 5.5	–	0.1	–	0.1	V
		I _{OL} = 100 µA	1.65	–	0.24	–	0.24	
		I _{OL} = 4 mA	2.3	–	0.3	–	0.3	
		I _{OL} = 8 mA	2.7	–	0.4	–	0.4	
		I _{OL} = 12 mA	3.0	–	0.4	–	0.4	
		I _{OL} = 16 mA	3.0	–	0.55	–	0.55	
		I _{OL} = 24 mA	4.5	–	0.6	–	0.6	
		I _{OL} = 32 mA						
I _I	Input Leakage Current	V _I = 0 to 5.5 V	3.6	–	±5.0	–	±5.0	µA
I _{OFF}	Power Off Leakage Current	V _I = 5.5 V or V _O = 5.5 V	0	–	10	–	10	µA
I _{CC}	Quiescent Supply Current	V _I = 5.5 V or GND	3.6	–	10	–	10	µA
ΔI _{CC}	Increase in I _{CC} per Input	V _{IH} = V _{CC} – 0.6 V	2.3 to 3.6	–	500	–	500	µA

AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Condition	V _{CC} (V)	T _A = -40°C to +85°C		T _A = -40°C to +125°C		Unit
				Min	Max	Min	Max	
t _{PLH} , t _{PHL}	Propagation Delay, CPn to (On or $\overline{\text{On}}$)	Waveform 1	1.65 to 1.95	–	12.5	–	12.5	ns
			2.3 to 2.7	–	8.4	–	8.4	
			2.7	–	8.0	–	8.0	
			3.0 to 3.6	–	7.0	–	7.0	
			4.5 to 5.5	–	5.0	–	5.0	
t _{PLH} , t _{PHL}	Propagation Delay, (SDn or CDn) to (On or $\overline{\text{On}}$)	Waveform 2	1.65 to 1.95	–	12.5	–	12.5	ns
			2.3 to 2.7	–	8.4	–	8.4	
			2.7	–	8.0	–	8.0	
			3.0 to 3.6	–	7.0	–	7.0	
			4.5 to 5.5	–	5.0	–	5.0	

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AC ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Test Condition	V _{CC} (V)	T _A = -40°C to +85°C		T _A = -40°C to +125°C		Unit
				Min	Max	Min	Max	
f _{max}	Clock Pulse Frequency	Waveform 1	1.65 to 1.95	90	–	90	–	MHz
			2.3 to 2.7	150	–	150	–	
			2.7	150	–	150	–	
			3.0 to 3.6	150	–	150	–	
			4.5 to 5.5	150	–	150	–	
t _s	Setup Time, HIGH or LOW Dn to CPn	Waveform 1	1.65 to 1.95	4.0	–	4.0	–	ns
			2.3 to 2.7	4.0	–	4.0	–	
			2.7	2.5	–	2.5	–	
			3.0 to 3.6	2.5	–	2.5	–	
			4.5 to 5.5	2.5	–	2.5	–	
t _h	Hold Time, HIGH or LOW Dn to CPn	Waveform 1	1.65 to 1.95	2.0	–	2.0	–	ns
			2.3 to 2.7	2.0	–	2.0	–	
			2.7	1.5	–	1.5	–	
			3.0 to 3.6	1.5	–	1.5	–	
			4.5 to 5.5	1.5	–	1.5	–	
t _w	Pulse Width, CPn HIGH or LOW	Waveform 4	1.65 to 1.95	4.0	–	4.0	–	ns
			2.3 to 2.7	4.0	–	4.0	–	
			2.7	3.3	–	3.3	–	
			3.0 to 3.6	3.3	–	3.3	–	
			4.5 to 5.5	3.3	–	3.3	–	
	Pulse Width, SDn or CDn LOW	Waveform 4	1.65 to 1.95	4.0	–	4.0	–	ns
			2.3 to 2.7	4.0	–	4.0	–	
			2.7	3.6	–	3.6	–	
			3.0 to 3.6	3.3	–	3.3	–	
			4.5 to 5.5	3.3	–	3.3	–	
t _{rec}	Recovery Time, SDn or CDn TO CPn	Waveform 3	1.65 to 1.95	4.5	–	4.5	–	ns
			2.3 to 2.7	4.5	–	4.5	–	
			2.7	3.0	–	3.0	–	
			3.0 to 3.6	2.5	–	2.5	–	
			4.5 to 5.5	2.5	–	2.5	–	
t _{OSHL} , t _{OSLH}	Output to Output Skew		1.65 to 1.95	–	–	–	–	ns
			2.3 to 2.7	–	–	–	–	
			2.7	–	–	–	–	
			3.0 to 3.6	–	1.0	–	1.0	
			4.5 to 5.5	–	–	–	–	

5. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

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DYNAMIC SWITCHING CHARACTERISTICS

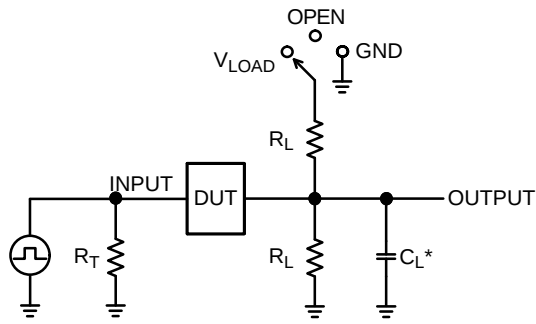
Symbol	Characteristic	Condition	$T_A = +25^{\circ}\text{C}$			Units
			Min	Typ	Max	
V_{OLP}	Dynamic LOW Peak Voltage (Note 6)	$V_{CC} = 3.3\text{ V}, C_L = 50\text{ pF}, V_{IH} = 3.3\text{ V}, V_{IL} = 0\text{ V}$		0.8		V
		$V_{CC} = 2.5\text{ V}, C_L = 30\text{ pF}, V_{IH} = 2.5\text{ V}, V_{IL} = 0\text{ V}$		0.6		V
V_{OLV}	Dynamic LOW Valley Voltage (Note 6)	$V_{CC} = 3.3\text{ V}, C_L = 50\text{ pF}, V_{IH} = 3.3\text{ V}, V_{IL} = 0\text{ V}$		-0.8		V
		$V_{CC} = 2.5\text{ V}, C_L = 30\text{ pF}, V_{IH} = 2.5\text{ V}, V_{IL} = 0\text{ V}$		-0.6		V

6. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 3.3\text{ V}, V_I = 0\text{ V or } V_{CC}$	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3\text{ V}, V_O = 0\text{ V or } V_{CC}$	8	pF
C_{PD}	Power Dissipation Capacitance	10 MHz, $V_{CC} = 3.3\text{ V}, V_I = 0\text{ V or } V_{CC}$	25	pF

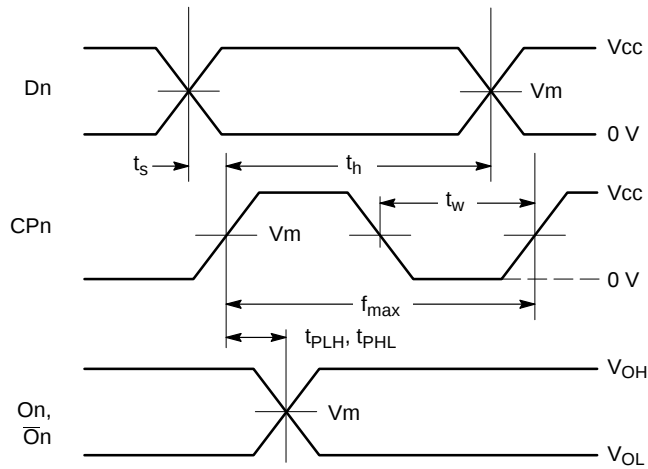
MC74LCX74



C_L includes probe and jig capacitance
 R_T is Z_{OUT} of pulse generator (typically 50 Ω)
 $f = 1$ MHz, $t_W = 500$ ns

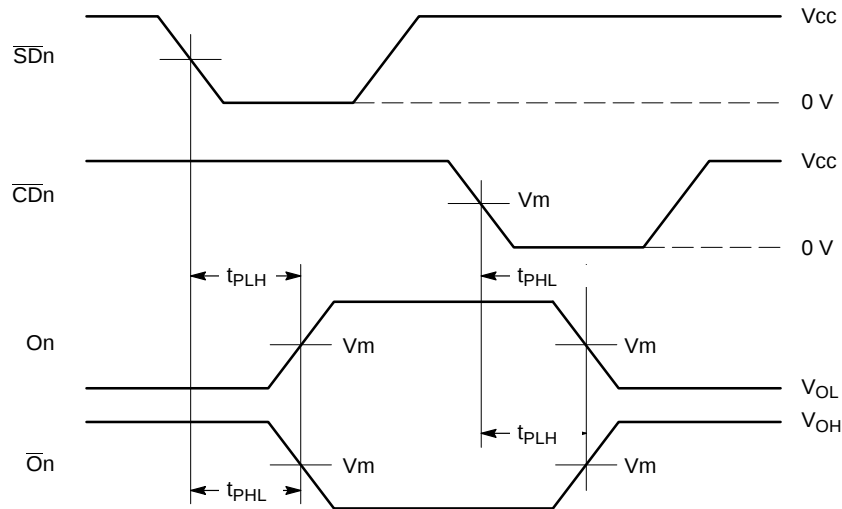
Test	Switch Position
t_{PLH} / t_{PHL}	Open
t_{PLZ} / t_{PZL}	V_{LOAD}
t_{PHZ} / t_{PZH}	GND

Figure 3. Test Circuit



WAVEFORM 1 – PROPAGATION DELAYS, SETUP AND HOLD TIMES

$t_R = t_F = 2.5$ ns, 10% to 90%; $f = 1$ MHz; $t_W = 500$ ns

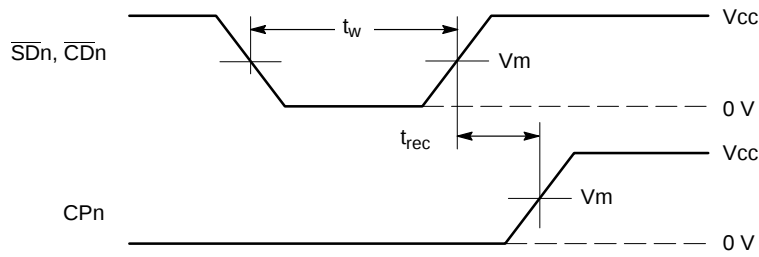


WAVEFORM 2 – PROPAGATION DELAYS

$t_R = t_F = 2.5$ ns, 10% to 90%; $f = 1$ MHz; $t_W = 500$ ns

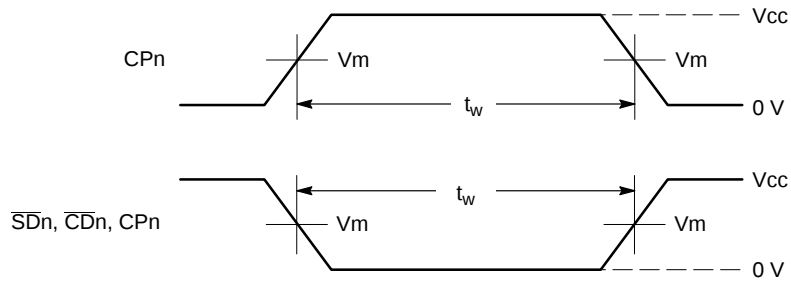
Figure 4. AC Waveforms

MC74LCX74



WAVEFORM 3 – RECOVERY TIME

$t_R = t_F = 2.5$ ns from 10% to 90%; $f = 1$ MHz; $t_W = 500$ ns



WAVEFORM 4 – PULSE WIDTH

$t_R = t_F = 2.5$ ns (or fast as required) from 10% to 90%;
Output requirements: $V_{OL} \leq 0.8$ V, $V_{OH} \geq 2.0$ V

V_{CC} , V	R_L , Ω	C_L , pF	V_{LOAD}	V_m , V	V_Y , V
1.65 to 1.95	500	30	$2 \times V_{CC}$	$V_{CC} / 2$	0.15
2.3 to 2.7	500	30	$2 \times V_{CC}$	$V_{CC} / 2$	0.15
2.7	500	50	6 V	1.5	0.3
3.0 to 3.6	500	50	6 V	1.5	0.3
4.5 to 5.5	500	50	$2 \times V_{CC}$	$V_{CC} / 2$	0.3

Figure 4. AC Waveforms (Continued)

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MC74LCX74DG	LCX74G	SOIC-14 (Pb-Free, Halide Free)	55 Units / Rail
MC74LCX74DR2G	LCX74G	SOIC-14 (Pb-Free, Halide Free)	2500 Units / Tape & Reel
MC74LCX74DTG	LCX 74	TSSOP-14 (Pb-Free, Halide Free)	96 Units / Rail
MC74LCX74DTR2G	LCX 74	TSSOP-14 (Pb-Free, Halide Free)	2500 Units / Tape & Reel

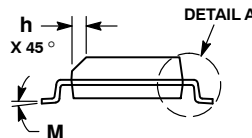
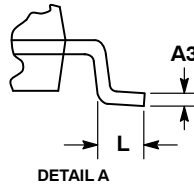
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.



SOIC-14 NB
CASE 751A-03
ISSUE L

DATE 03 FEB 2016

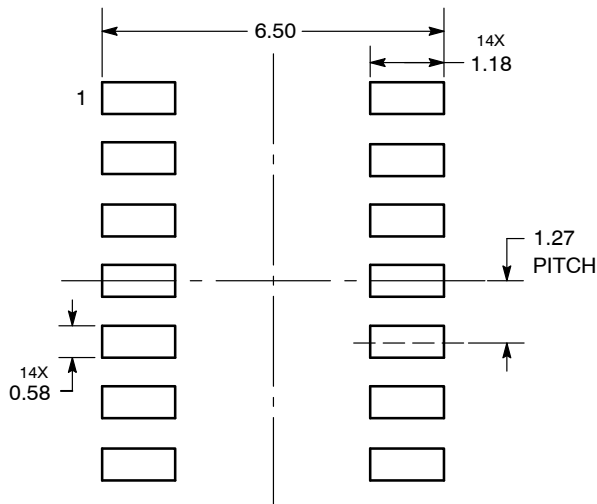


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0°	7°	0°	7°

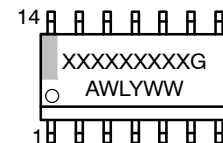
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*



XXXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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CASE 751A-03
ISSUE L

DATE 03 FEB 2016

STYLE 1:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. NO CONNECTION
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. NO CONNECTION
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 2:
CANCELLED

STYLE 3:
PIN 1. NO CONNECTION
2. ANODE
3. ANODE
4. NO CONNECTION
5. ANODE
6. NO CONNECTION
7. ANODE
8. ANODE
9. ANODE
10. NO CONNECTION
11. ANODE
12. ANODE
13. NO CONNECTION
14. COMMON CATHODE

STYLE 4:
PIN 1. NO CONNECTION
2. CATHODE
3. CATHODE
4. NO CONNECTION
5. CATHODE
6. NO CONNECTION
7. CATHODE
8. CATHODE
9. CATHODE
10. NO CONNECTION
11. CATHODE
12. CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 5:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. NO CONNECTION
7. COMMON ANODE
8. COMMON CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 6:
PIN 1. CATHODE
2. CATHODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE
7. CATHODE
8. ANODE
9. ANODE
10. ANODE
11. ANODE
12. ANODE
13. ANODE
14. ANODE

STYLE 7:
PIN 1. ANODE/CATHODE
2. COMMON ANODE
3. COMMON CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. ANODE/CATHODE
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. COMMON CATHODE
12. COMMON ANODE
13. ANODE/CATHODE
14. ANODE/CATHODE

STYLE 8:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. ANODE/CATHODE
7. COMMON ANODE
8. COMMON ANODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. NO CONNECTION
12. ANODE/CATHODE
13. ANODE/CATHODE
14. COMMON CATHODE

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TSSOP-14 WB
CASE 948G
ISSUE C

DATE 17 FEB 2016

SCALE 2:1

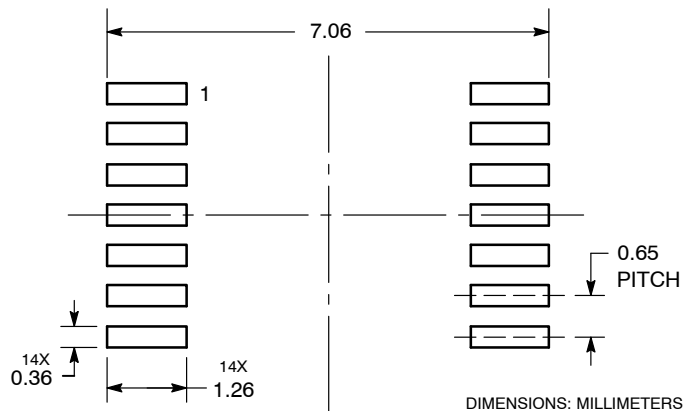


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

RECOMMENDED
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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